

CSCE 612

Lab 3

Development and Simulation of Full Standard Cell Library

Due Date: 3/14/06

Introduction

In this lab you will design and simulate a full standard cell library. While the tutorials demonstrated the design of a minimal cell library, your cell library will contain several additional cells in order to achieve more efficient logic synthesis.

Table 1 outlines a minimal set of cells for your library, but you may add additional cells if you wish (adding additional cells may make it easier for you to meet your design goals for the course project). You may implement each cell however you wish as long as each implements the specified digital logic function.

Name	Description
INVX1	inverter, $NW=10\lambda$, $PW=20\lambda$
INVX2	inverter, $NW=20\lambda$, $PW=40\lambda$
INVX4	inverter, $NW=40\lambda$, $PW=80\lambda$
INVX8	inverter, $NW=80\lambda$, $PW=160\lambda$
BUF2	buffer (2 series inverters), $NW=20\lambda$, $PW=40\lambda$
BUF4	buffer (2 series inverters), $NW=40\lambda$, $PW=80\lambda$
CLKBUF1	clock buffer (4 series tapered inverters) $NW=[10, 20, 40, 40]\lambda$, $PW=[20, 40, 80, 80]\lambda$
TINVX2	tristate inverter (see Fig. 1.26 in textbook) $NW=20\lambda$, $PW=40\lambda$
NAND2X1	2-input NAND gate, $NW=10\lambda$, $PW=20\lambda$
NAND3X1	3-input NAND gate, $NW=10\lambda$, $PW=20\lambda$
NAND4X1	4-input NAND gate, $NW=10\lambda$, $PW=20\lambda$
NOR2X1	2-input NOR gate, $NW=10\lambda$, $PW=20\lambda$
NOR3X1	3-input NOR gate, $NW=10\lambda$, $PW=20\lambda$
NOR4X1	4-input NOR gate, $NW=10\lambda$, $PW=20\lambda$
XOR2X1	2-input XOR gate, $NW=10\lambda$, $PW=20\lambda$
AOIX1	3-input AND-OR-INVERT, $NW=10\lambda$, $PW=20\lambda$
OAIX1	3-input OR-AND-INVERT, $NW=10\lambda$, $PW=20\lambda$
FAX1	1-bit full adder, $NW=10\lambda$, $PW=20\lambda$
HAX1	1-bit half adder, $NW=10\lambda$, $PW=20\lambda$
MUX2	2-input MUX, $NW=10\lambda$, $PW=20\lambda$
FILL	fill cell (layout only)
DFFX1	rising or falling-edge D-flip-flop (may or may not have built-in asynchronous reset), $NW=10\lambda$, $PW=20\lambda$

Table 1

Design Flow

Tutorials 1 (*schematic design*), 2 (*layout design*) and 3 (*preparing your cell library*) will assist you in developing your cell library. Tutorials 4 (*characterization*) and 5 (*abstract generation*) will assist you in performing the post-processing steps in order to prepare your library for use in the synthesis and place-and-route tools.

Requirements

For each cell, you must perform the following design steps:

1. Design cell schematic
2. Exhaustively test all possible input combinations using a test bench
3. Design cell layout

4. Extract layout
5. Perform LVS and analog extraction
6. Repeat testbench using analog_extracted view

Once you've completed design and testing, you must characterize your library using SignalStorm and generate abstracts with Abstract Generator.

Make sure you design each of your cells on a reasonable routing grid. You don't have to use the routing grid from the tutorials (4.5 μ grid/2.25 μ offset), but keep in mind that the minimum routing grid for metal1 and metal2 is 2.1 μ m and the minimum routing grid for metal3 is 2.7 μ m based on the minimum contact sizes and minimum metal spacing (for routing tracks).

What to Submit

Submit the cell schematic, layout, testbench simulation plot, and HTML output (from SignalStorm) for each of your cells.